

C3D04065A–Silicon Carbide Schottky Diode

Z-REC™ RECTIFIER

$$\begin{aligned} V_{RRM} &= 650 \text{ V} \\ I_{F(AVG)} &= 4 \text{ A} \\ Q_c &= 8.5 \text{ nC} \end{aligned}$$

Features

- 650-Volt Schottky Rectifier
- Optimized for PFC Boost Diode Application
- Zero Reverse Recovery Current
- Zero Forward Recovery Voltage
- High-Frequency Operation
- Temperature-Independent Switching Behavior
- Extremely Fast Switching
- Positive Temperature Coefficient on V_F

Benefits

- Replace Bipolar with Unipolar Rectifiers
- Essentially No Switching Losses
- Higher Efficiency
- Reduction of Heat Sink Requirements
- Parallel Devices Without Thermal Runaway

Applications

- Switch Mode Power Supplies
- Power Factor Correction
 - Typical PFC P_{out} : 400W-600W

Package



TO-220-2



Part Number	Package	Marking
C3D04065A	TO-220-2	C3D04065

Maximum Ratings

Symbol	Parameter	Value	Unit	Test Conditions	Note
V_{RRM}	Repetitive Peak Reverse Voltage	650	V		
V_{RSM}	Surge Peak Reverse Voltage	650	V		
V_{DC}	DC Blocking Voltage	650	V		
$I_{F(AVG)}$	Average Forward Current	4	A	$T_c < 160^\circ\text{C}$	
I_{FRM}	Repetitive Peak Forward Surge Current	22 17	A	$T_c = 25^\circ\text{C}$, $t_p = 10 \text{ mS}$, Half Sine Wave $D = 0.3$ $T_c = 110^\circ\text{C}$, $t_p = 10 \text{ mS}$, Half Sine Wave $D = 0.3$	
I_{FSM}	Non-Repetitive Peak Forward Surge Current	31.9 28.5	A	$T_c = 25^\circ\text{C}$, $t_p = 10 \text{ mS}$, Half Sine Wave $D = 0.3$ $T_c = 110^\circ\text{C}$, $t_p = 10 \text{ mS}$, Half Sine Wave $D = 0.3$	
I_{FSM}	Non-Repetitive Peak Forward Surge Current	110	A	$T_c = 25^\circ\text{C}$, $t_p = 10 \mu\text{S}$, Pulse	
P_{tot}	Power Dissipation	75 32.5	W	$T_c = 25^\circ\text{C}$ $T_c = 110^\circ\text{C}$	
T_J, T_{stg}	Operating Junction and Storage Temperature	-55 to +175	$^\circ\text{C}$		
	TO-220 Mounting Torque	1 8.8	Nm lbf-in	M3 Screw 6-32 Screw	

Electrical Characteristics

Symbol	Parameter	Typ.	Max.	Unit	Test Conditions	Note
V_F	Forward Voltage	1.5 1.8	1.8 2.4	V	$I_F = 4\text{ A}$ $T_J = 25^\circ\text{C}$ $I_F = 4\text{ A}$ $T_J = 175^\circ\text{C}$	
I_R	Reverse Current	12 24	60 120	μA	$V_R = 650\text{ V}$ $T_J = 25^\circ\text{C}$ $V_R = 650\text{ V}$ $T_J = 175^\circ\text{C}$	
Q_C	Total Capacitive Charge	8.5		nC	$V_R = 650\text{ V}$, $I_F = 4\text{ A}$ $di/dt = 500\text{ A}/\mu\text{s}$ $T_J = 25^\circ\text{C}$	
C	Total Capacitance	251 22 21		pF	$V_R = 0\text{ V}$, $T_J = 25^\circ\text{C}$, $f = 1\text{ MHz}$ $V_R = 200\text{ V}$, $T_J = 25^\circ\text{C}$, $f = 1\text{ MHz}$ $V_R = 400\text{ V}$, $T_J = 25^\circ\text{C}$, $f = 1\text{ MHz}$	

Note:

1. This is a majority carrier diode, so there is no reverse recovery charge.

Thermal Characteristics

Symbol	Parameter	Typ.	Unit
$R_{\theta JC}$	TO-220 Package Thermal Resistance from Junction to Case	2.02	$^\circ\text{C}/\text{W}$

Typical Performance

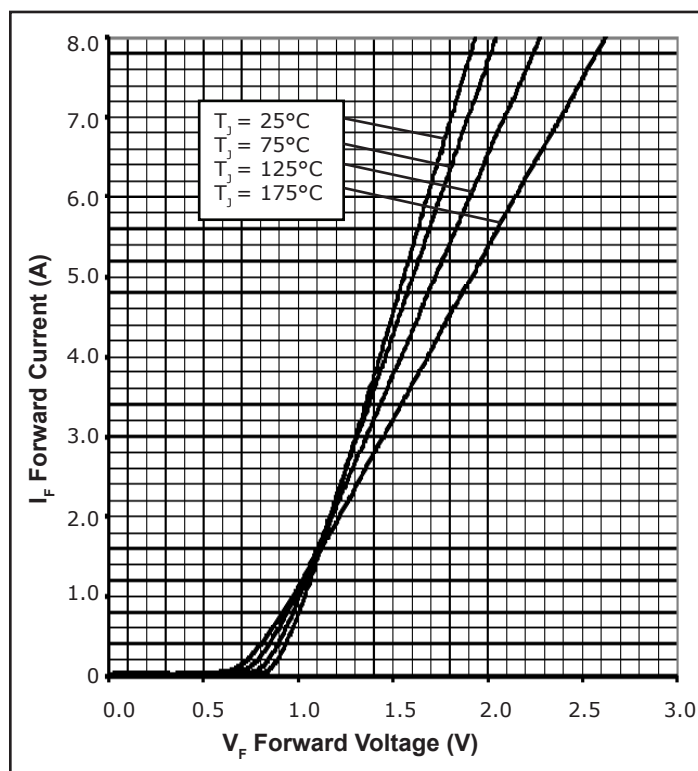


Figure 1. Forward Characteristics

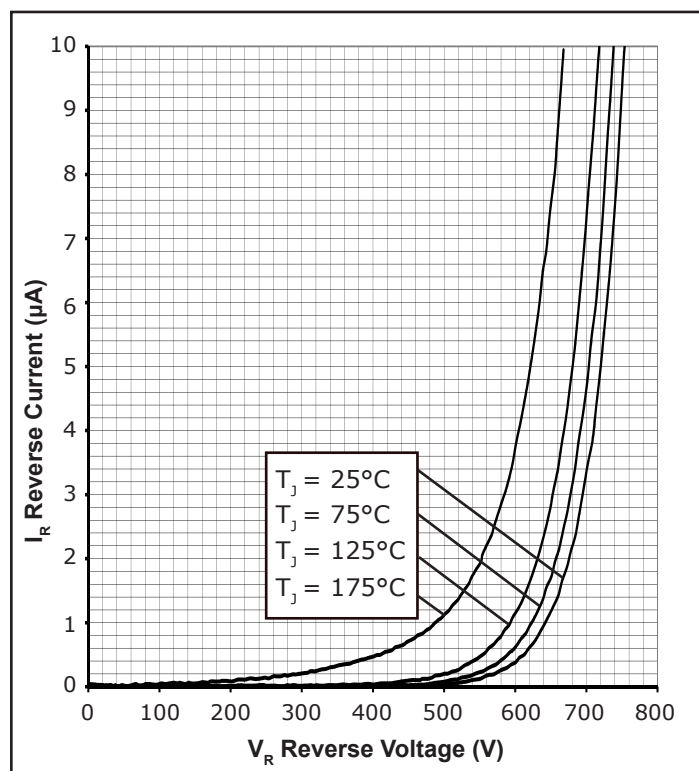


Figure 2. Reverse Characteristics

Typical Performance

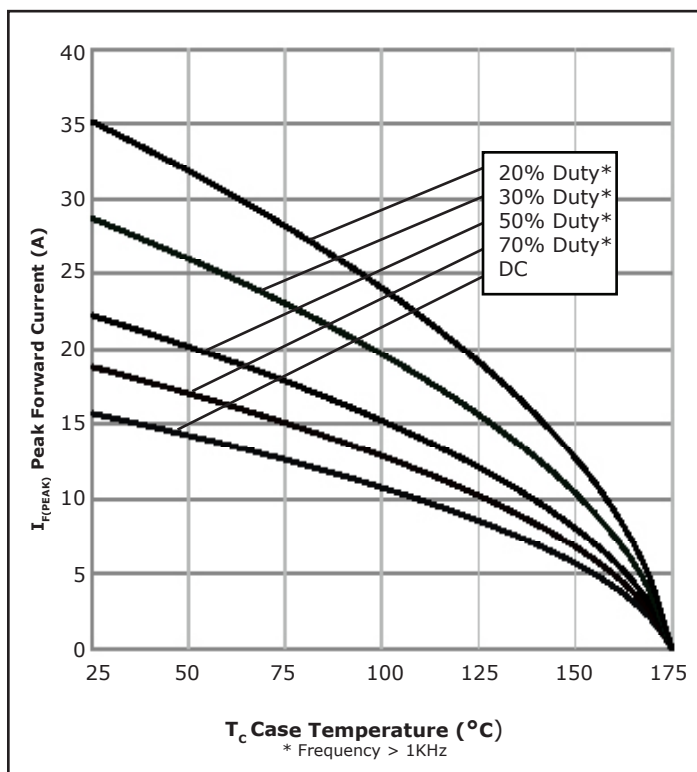


Figure 3. Current Derating

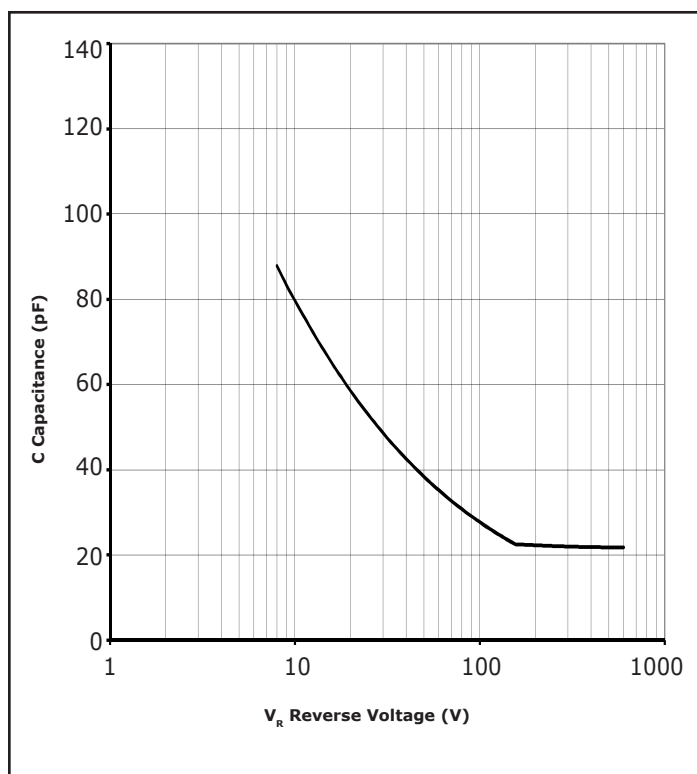


Figure 4. Capacitance vs. Reverse Voltage

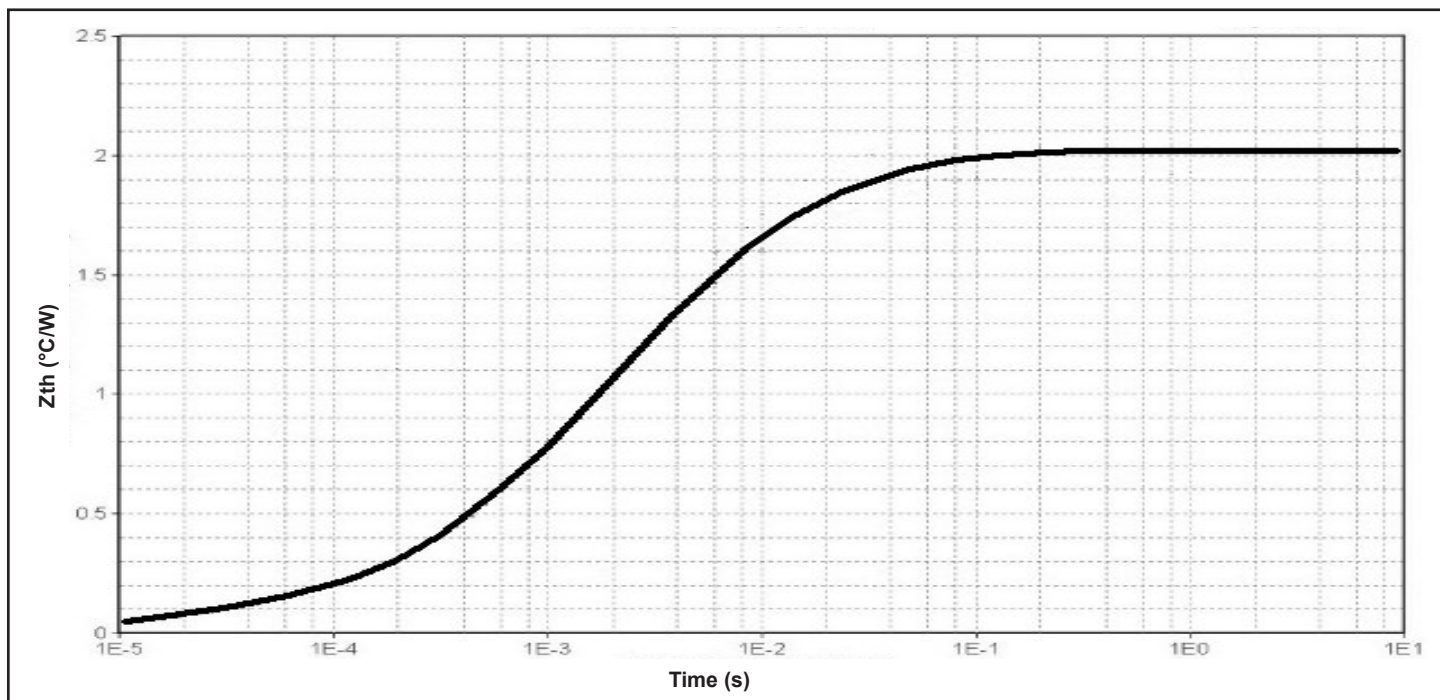


Figure 5. Transient Thermal Impedance

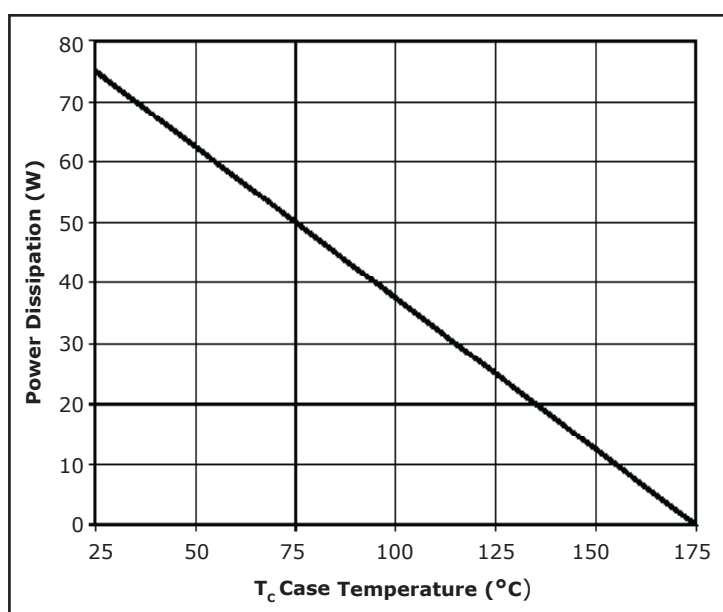
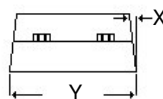
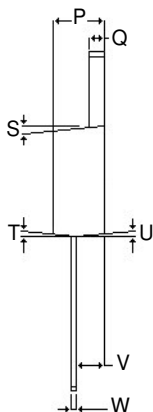
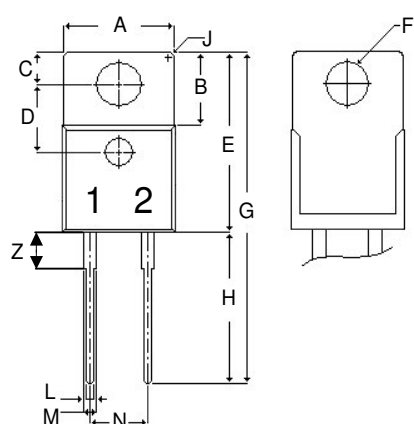
Typical Performance

Figure 6. Power Derating

Package Dimensions

Package TO-220-2

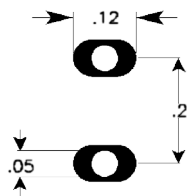


POS	Inches		Millimeters	
	Min	Max	Min	Max
A	.381	.410	9.677	10.414
B	.235	.255	5.969	6.477
C	.100	.120	2.540	3.048
D	.223	.337	5.664	8.560
E	.590	.615	14.986	15.621
F	.143	.153	3.632	3.886
G	1.105	1.147	28.067	29.134
H	.500	.550	12.700	13.970
J	R 0.197		R 0.197	
L	.025	.036	.635	.914
M	.045	.055	1.143	1.397
N	.195	.205	4.953	5.207
P	.165	.185	4.191	4.699
Q	.048	.054	1.219	1.372
S	3°	6°	3°	6°
T	3°	6°	3°	6°
U	3°	6°	3°	6°
V	.094	.110	2.388	2.794
W	.014	.025	.356	.635
X	3°	5.5°	3°	5.5°
Y	.385	.410	9.779	10.414
z	.130	.150	3.302	3.810

NOTE:

1. Dimension L, M, W apply for Solder Dip Finish

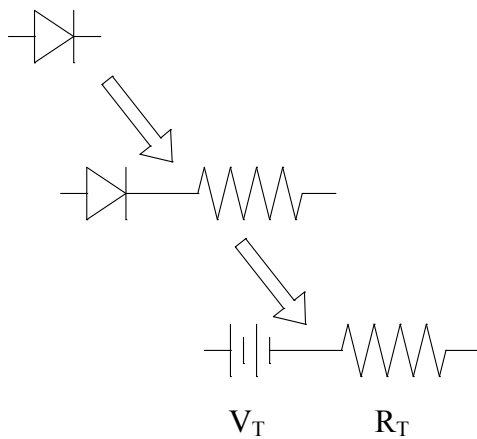
Recommended Solder Pad Layout



TO-220-2

Part Number	Package	Marking
C3D04065A	TO-220-2	C3D04065

Diode Model



$$V_{fT} = V_T + I_f \cdot R_T$$

$$V_T = 0.98 + (T_J \cdot -1.8 \cdot 10^{-3})$$

$$R_T = 0.10 + (T_J \cdot 9.16 \cdot 10^{-4})$$

Note: T_J = Diode Junction Temperature In Degrees Celcius

"The levels of environmentally sensitive, persistent biologically toxic (PBT), persistent organic pollutants (POP), or otherwise restricted materials in this product are below the maximum concentration values (also referred to as the threshold limits) permitted for such substances, or are used in an exempted application, in accordance with EU Directive 2002/95/EC on the restriction of the use of certain hazardous substances in electrical and electronic equipment (RoHS), as amended through April 21, 2006.

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